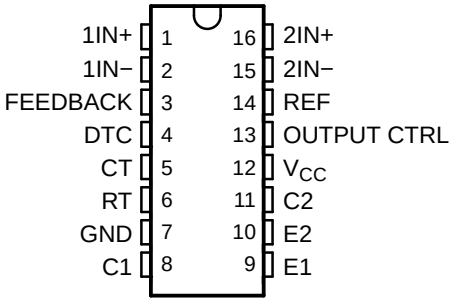
FEATURES

- **Complete PWM Power-Control Circuitry**
- **Uncommitted Outputs for 200-mA Sink or Source Current**
- **Output Control Selects Single-Ended or Push-Pull Operation**
- **Internal Circuitry Prohibits Double Pulse at Either Output**
- **Variable Dead Time Provides Control Over Total Range**
- **Internal Regulator Provides a Stable 5-V Reference Supply With 5% Tolerance**
- **Circuit Architecture Allows Easy Synchronization**

D, DB, N, NS, OR PW PACKAGE
(TOP VIEW)



DESCRIPTION

The TL494 incorporates all the functions required in the construction of a pulse-width-modulation (PWM) control circuit on a single chip. Designed primarily for power-supply control, this device offers the flexibility to tailor the power-supply control circuitry to a specific application.

The TL494 contains two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, a 5-V, 5%-precision regulator, and output-control circuits.

The error amplifiers exhibit a common-mode voltage range from –0.3 V to V_{CC} – 2 V. The dead-time control comparator has a fixed offset that provides approximately 5% dead time. The on-chip oscillator can be bypassed by terminating RT to the reference output and providing a sawtooth input to CT, or it can drive the common circuits in synchronous multiple-rail power supplies.

The uncommitted output transistors provide either common-emitter or emitter-follower output capability. The TL494 provides for push-pull or single-ended output operation, which can be selected through the output-control function. The architecture of this device prohibits the possibility of either output being pulsed twice during push-pull operation.

The TL494C is characterized for operation from 0°C to 70°C. The TL494I is characterized for operation from –40°C to 85°C.

AVAILABLE OPTIONS

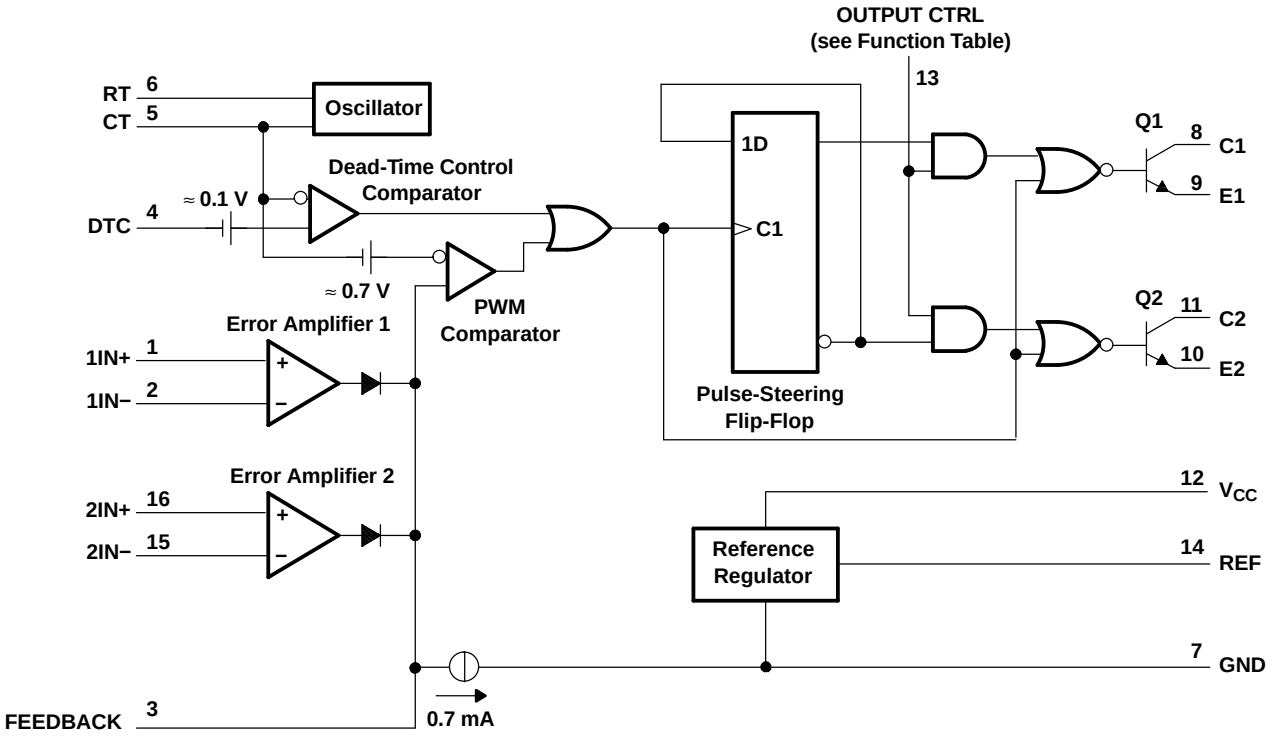
T_A	PACKAGED DEVICES(1)				
	SMALL OUTLINE (D)	PLASTIC DIP (N)	SMALL OUTLINE (NS)	SHRINK SMALL OUTLINE (DB)	THIN SHRINK SMALL OUTLINE (PW)
0°C to 70°C	TL494CD	TL494CN	TL494CNS	TL494CDB	TL494CPW
–40°C to 85°C	TL494ID	TL494IN	—	—	—

(1) The D, DB, NS, and PW packages are available taped and reeled. Add the suffix R to device type (e.g., TL494CDR).

FUNCTION TABLE

INPUT TO OUTPUT CTRL	OUTPUT FUNCTION
V_I = GND	Single-ended or parallel output
$V_I = V_{ref}$	Normal push-pull operation

FUNCTIONAL BLOCK DIAGRAM



Absolute Maximum Ratings[1]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage[2]			41	V
V_I	Amplifier input voltage			V_{CC} + 0.3	V
V_O	Collector output voltage			41	V
I_O	Collector output current			250	mA
θ_{JA}	Package thermal impedance[3][4]	D package		73	°C/W
		DB package		82	
		N package		67	
		NS package		64	
		PW package		108	
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds			260	°C
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to the network ground terminal.
(3) Maximum power disipation is a function of $T_J(max)$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperatire is $P_D = (T_J(max) – T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

			MIN	MAX	UNIT
V_{CC}	Supply voltage		7	40	V
V_I	Amplifier input voltage		–0.3	V_{CC} – 2	V
V_O	Collector output voltage			40	V
	Collector output current (each transistor)			200	mA
	Current into feedback terminal			0.3	mA
f_{OSC}	Oscillator frequency		1	300	kHz
C_T	Timing capacitor		0.47	10000	nF
R_T	Timing resistor		1.8	500	kΩ
T_A	Operating free-air temperature	TL494C	0	70	°C
		TL494I	–40	85	

Electrical Characteristics

over recommended operating free-air temperature range, V_{CC} = 15 V, f = 10 kHz (unless otherwise noted)

Reference Section

PARAMETER	TEST CONDITIONS(1)	TL494C, TL494I			UNIT
		MIN	TYP(2)	MAX	
Output voltage (REF)	I_O = 1 mA	4.75	5	5.25	V
Input regulation	V_{CC} = 7 V to 40 V		2	25	mV
Output regulation	I_O = 1 mA to 10 mA		1	15	mV
Output voltage change with temperature	ΔT_A = MIN to MAX		2	10	mV/V
Short-circuit output current(3)	REF = 0 V		25		mA

(1) For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
(2) All typical values, except for parameter changes with temperature, are at T_A = 25°C.
(3) Duration of short circuit should not exceed one second.

Oscillator Section

C_T = 0.01 μF, R_T = 12 kΩ (see Figure 1)

PARAMETER	TEST CONDITIONS(1)	TL494C, TL494I			UNIT
		MIN	TYP(2)	MAX	
Frequency			10		kHz
Standard deviation of frequency(3)	All values of V_{CC}, C_T, R_T, and T_A constant		100		Hz/kHz
Frequency change with voltage	V_{CC} = 7 V to 40 V, T_A = 25°C		1		Hz/kHz
Frequency change with temperature(4)	ΔT_A = MIN to MAX			10	Hz/kHz

(1) For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
(2) All typical values, except for parameter changes with temperature, are at T_A = 25°C.
(3) Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

$$\sigma = \sqrt{\frac{\sum_{n=1}^{N} (x_n - \overline{X})^2}{N - 1}}$$

(4) Temperature coefficient of timing capacitor and timing resistor are not taken into account.

Error-Amplifier Section

See Figure 2

PARAMETER	TEST CONDITIONS	TL494C, TL494I			UNIT
		MIN	TYP(1)	MAX	
Input offset voltage	V_O (FEEDBACK) = 2.5 V		2	10	mV
Input offset current	V_O (FEEDBACK) = 2.5 V		25	250	nA
Input bias current	V_O (FEEDBACK) = 2.5 V		0.2	1	μA
Common-mode input voltage range	V_{CC} = 7 V to 40 V	–0.3 to V_{CC} – 2			V
Open-loop voltage amplification	ΔV_O = 3 V, V_O = 0.5 V to 3.5 V, R_L = 2 kΩ	70	95		dB
Unity-gain bandwidth	V_O = 0.5 V to 3.5 V, R_L = 2 kΩ		800		kHz
Common-mode rejection ratio	ΔV_O = 40 V, T_A = 25°C	65	80		dB
Output sink current (FEEDBACK)	V_{ID} = –15 mV to –5 V, V (FEEDBACK) = 0.7 V	0.3	0.7		mA
Output source current (FEEDBACK)	V_{ID} = 15 mV to 5 V, V (FEEDBACK) = 3.5 V	–2			mA

(1) All typical values, except for parameter changes with temperature, are at T_A = 25°C.

Electrical Characteristics

over recommended operating free-air temperature range, V_{CC} = 15 V, f = 10 kHz (unless otherwise noted)

Output Section

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Collector off-state current		V_{CE} = 40 V, V_{CC} = 40 V		2	100	μA
Emitter off-state current		V_{CC} = V_C = 40 V, V_E = 0			–100	μA
Collector-emitter saturation voltage	Common emitter	V_E = 0, I_C = 200 mA		1.1	1.3	V
	Emitter follower	$V_{O(C1 \text{ or } C2)}$ = 15 V, I_E = –200 mA		1.5	2.5	
Output control input current		V_I = V_{ref}			3.5	mA

(1) All typical values, except for temperature coefficient, are at T_A = 25°C.

Dead-Time Control Section

See Figure 1

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Input bias current (DEAD-TIME CTRL)	V_I = 0 to 5.25 V		–2	–10	μA
Maximum duty cycle, each output	V_I (DEAD-TIME CTRL) = 0, C_T = 0.01 μF, R_T = 12 kΩ		45		%
Input threshold voltage (DEAD-TIME CTRL)	Zero duty cycle		3	3.3	V
	Maximum duty cycle	0			

(1) All typical values, except for temperature coefficient, are at T_A = 25°C.

PWM Comparator Section

See Figure 1

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Input threshold voltage (FEEDBACK)	Zero duty cyle		4	4.5	V
Input sink current (FEEDBACK)	V (FEEDBACK) = 0.7 V	0.3	0.7		mA

(1) All typical values, except for temperature coefficient, are at T_A = 25°C.

Total Device

PARAMETER	TEST CONDITIONS		MIN	TYP(1)	MAX	UNIT
Standby supply current	R_T = V_{ref}, All other inputs and outputs open	V_{CC} = 15 V		6	10	mA
		V_{CC} = 40 V		9	15	
Average supply current	V_I (DEAD-TIME CTRL) = 2 V, See Figure 1			7.5		mA

(1) All typical values, except for temperature coefficient, are at T_A = 25°C.

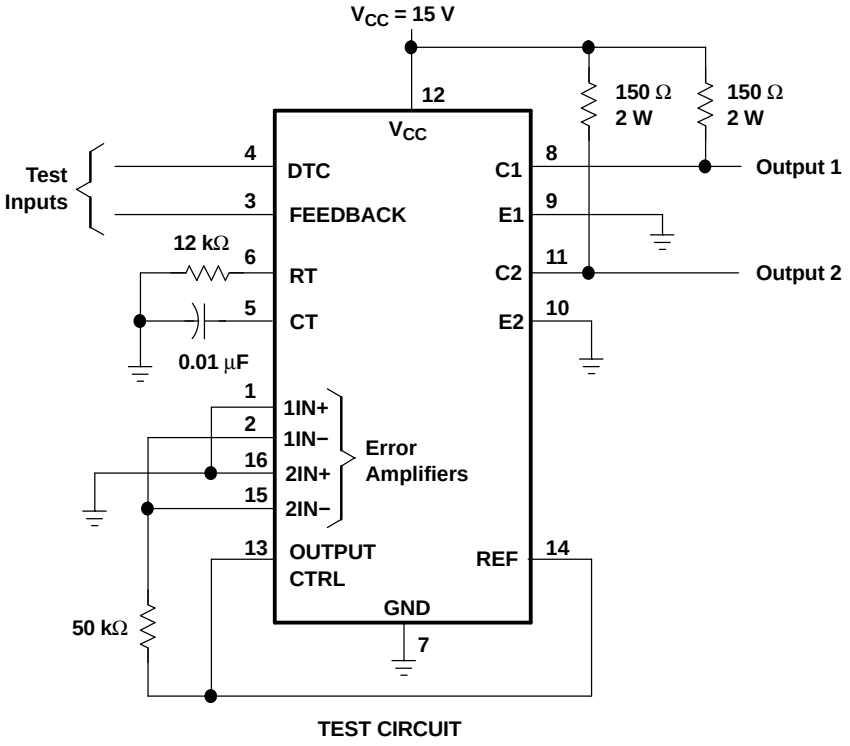
Switching Characteristics

T_A = 25°C

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Rise time	Common-emitter configuration, See Figure 3		100	200	ns
Fall time			25	100	ns
Rise time	Emitter-follower configuration, See Figure 4		100	200	ns
Fall time			40	100	ns

(1) All typical values, except for temperature coefficient, are at T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION



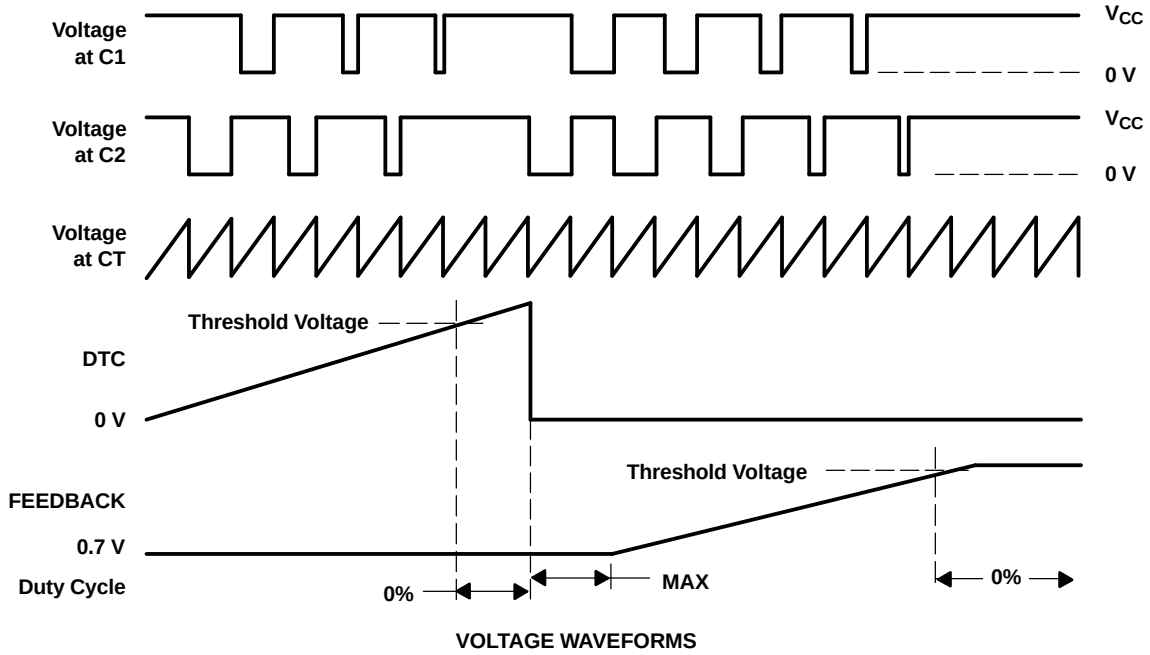


Figure 1. Operational Test Circuit and Waveforms

PARAMETER MEASUREMENT INFORMATION

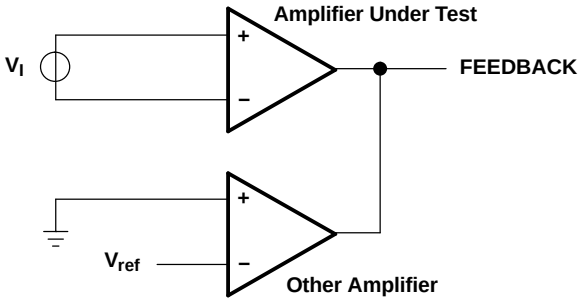
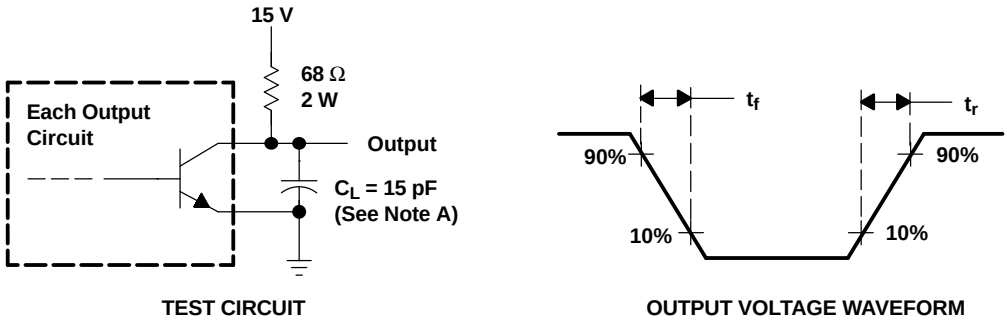
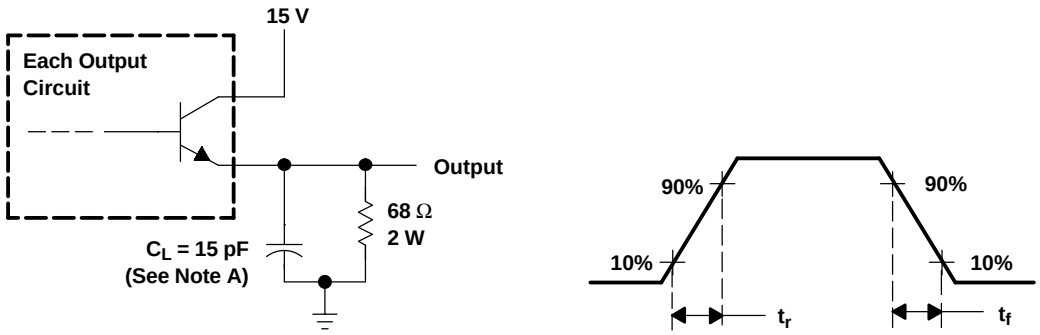


Figure 2. Amplifier Characteristics



NOTE A: C_L includes probe and jig capacitance.

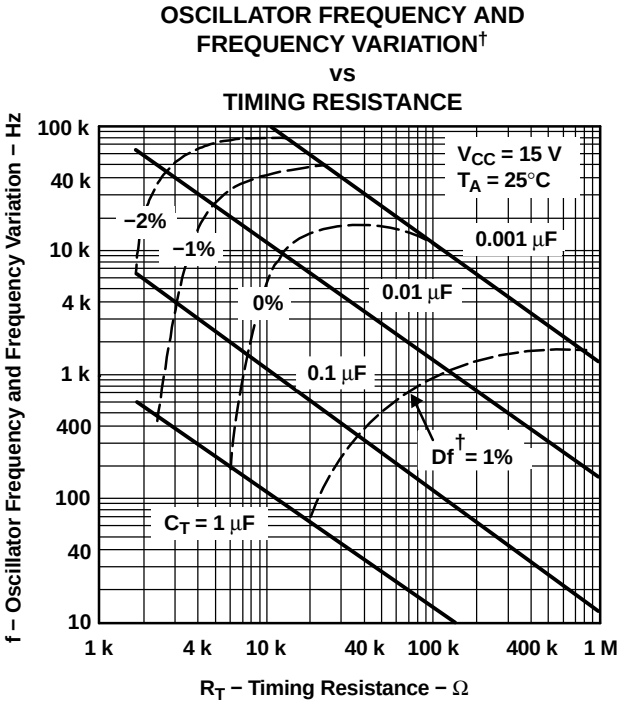
Figure 3. Common-Emitter Configuration



NOTE A: C_L includes probe and jig capacitance.

Figure 4. Emitter-Follower Configuration

TYPICAL CHARACTERISTICS



† Frequency variation (Δf) is the change in oscillator frequency that occurs over the full temperature range.

Figure 5.

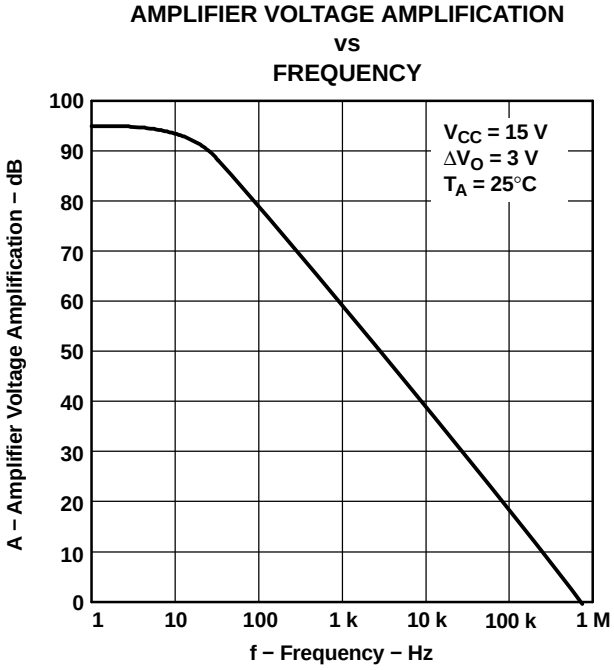


Figure 6.